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Inclosure Material:

Metal all transistor

Overall Length:

2.578 inches all transistor

Mounting Facility Quantity:

1 all transistor

Internal Configuration:

Junction contact all transistor

Electrode Internally-electrically Connected To Case:

Collector all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Threaded stud all transistor

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

1.047 inches all transistor and 1.078 inches all transistor

Thread Size:

0.500 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

200.0 collector to emitter voltage, dc all transistor

Current Rating Per Characteristic:

10.00 amperes source cutoff current all transistor and 30.00 amperes source cutoff current nanoamperes all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Thread Series Designator:

Unf all transistor

Terminal Type And Quantity:

2 tab, solder lug all transistor and 1 wire hook all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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